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U.S. PATENT DOCUMENTS						
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FOREIGN PATENT DOCUMENTS						
	DOCUMENT NUMBER	DATE	COUNTRY/NAME	CLASS	SUB CLASS	TRANSLATION YES NO
OTHER DOCUMENTS						
MT	Article entitled: Nb Oxide Thin Film Resistors; by Wilson <i>et al.</i> , published in IEEE Transactions on Applied Superconductivity, Vol.9 No. 2, June 1999, 1724-1726.					
MT	Article entitled: Properties of Ru-Ta Alloys as Gate Electrodes For NMOS and PMOS Silicon Devices, by Zhong <i>et al.</i> , IEEE, 2001 , 4 pages					
MT	Article entitled: Tunable Work Function Molybdenum Gate Technology for FDSOI-CMOS, by Ranade <i>et al.</i> , IEEE 2002 , 4 pages .					
MT	Article entitled: A Phase Map for Sputter Deposited Niobium Oxides, by Lee and Aita, published in the Journal of Applied Physics, Vol. 70, No. 4, 15 August 1991 , 2094-2103.					
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